CYPRESS SEMICONDUCTOR

PRODUCT CHANGE NOTIFICATION

PCN:020027 DATE: October 25, 2002

Subject: Fab Location change for IMIZ9972/IMIZ9973/IMIZ9974/IMIB9940/IMIZ9948 from

IBM to Chartered Semiconductor

To:

Description of change:

The Fab location will be changed for devices IMIZ9972, IMIZ9973, IMIZ9974, IMIB9940, IMIZ9948 from IBM to Chartered Semiconductor Manufacturing. Refer to the table below for ordering part#

OLD PART#	NEW ORDERING PART#
IMIB9940	CY29940
IMIZ9948	CY29948
IMIZ9972	CY29972
IMIZ9973	CY29973
IMIZ9974	CY29974

Benefit of change:

Improved availability and long term support.

Qualification status:

Completed. QTP# I000002

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Sample status:

Contact our sales office for samples

CYPRESS SEMICONDUCTOR

PRODUCT CHANGE NOTIFICATION

PCN:020027

DATE: October 25, 2002

Subject: Fab Location change for IMIZ9972/ IMIZ9973/IMI to Chartered Semiconductor	IZ9974/IMIB9940/IMIZ9948 from IBM
Cypress part numbers affected: IMIZ9972, IMIZ9973, IMIZ9974, IMIB9940, IMIZ9948	
Customer part numbers affected:	
Approximate Implementation Date: Production release of the new product will be implemented or WW 02 2003.	as per your response requirements
Response Required:	
Sincerely,	
	Al Laxman PCN Process Manager



CYPRESS

QUALIFICATION SUMMARY QTP# 1000002

Cypress Semiconductor 3901 North First Street San Jose, CA 95134 Phone: (408) 943-2600 Fax: (408) 943-2796

DIE QUALIFICATION TEST RESULTS

D35C/E35C/F35C base die platform (0.35 uM, 3 layers metal, CMOS, CSM-Singapore)

Test	Military or Industry Standard	Conditions	Test Points	Test Results	Comments
Life Test	MIL-STD-883 Method 1005	150 ^o C/3.3V	168 332	0/116 0/116	Lot C1061-D35C
Life Test	MIL-STD-883 Method 1005	150 ^o C/3.3V	72 596	0/116 0/116	Lot C1024-D35C
Life Test	MIL-STD-883 Method 1005	150 ^o C/3.3V	168	0/116	Lot C1130-D35C
ESD	MIL-STD-883 Method 3015	НВМ	2000V 3000V 4000V 5000V	0/3 0/3 0/3 0/3	Lot C1214-D35C
Latch-up	JESD78		200 Ma	0/5	Lot C1214-D35C
ESD	MIL-STD-883 Method 3015	НВМ	2000V 3000V 4000V	0/3 0/3 0/2	Lot C1281-E35C
Latch-up	JESD78		200 mA	0/5	Lot C1281-E35C
ESD	MIL-STD-883 Method 3015	НВМ	2000V 3000V 4000V	0/3 0/3 0/2	Lot C1189-F35C
Latch-up	JESD78		200 mA	0/5	Lot C1189-F35C

PACKAGE QUALIFICATION TEST RESULTS

SOIC ,0.150 wide

Test	Military or Industry	Conditions	Test	Test Results	Comments
	Standard		Points		
Temperature	MIL-STD-883	500 cycles,	500	0/76	Preconditioned
Cycle	Method 1010	-65/+ 150 ^O C			Units, CWT, lot C1179
Pressure Pot	JEDEC Std. 22	168 Hours, 100%	168	0/76	Preconditioned
	Test Method 102	RH, 121 ⁰ C, 2 atm			Units, CWT, lot C1179
Temperature	MIL-STD-883	500 cycles,	500	0/76	Preconditioned
Cycle	Method 1010	-65/+ 150 ^O C			Units, SPEL, lot T2959
Pressure Pot	JEDEC Std. 22	168 Hours, 100%	168	0/76	Preconditioned
	Test Method 102	RH, 121 ⁰ C, 2 atm			Units, SPEL, lot T2959
Temperature	MIL-STD-883	500 cycles,	500	0/76	Preconditioned
Cycle	Method 1010	-65/+ 150 ^O C			Units, CWT, lot B6399
Pressure Pot	JEDEC Std. 22	168 Hours, 100%	168	0/76	Preconditioned
	Test Method 102	RH, 121 ⁰ C, 2 atm			Units, CWT, lot B6399
Temperature	MIL-STD-883	500 cycles,	500	0/76	Preconditioned
Cycle	Method 1010	-65/+ 150 ^O C			Units, SIG-K, lot F5216
Pressure Pot	JEDEC Std. 22	168 Hours, 100%	168	0/76	Preconditioned
	Test Method 102	RH, 121 ⁰ C, 2 atm			Units, SIG-K, lot F5216
Physical Dimension	JEDEC Spec.	Applicable drawing	N/A	0/12	Performed by CWT
Resistance to	MIL-STD-883		N/A	0/12	Performed by CWT
Solvent	Method 2015				
Solderability	MIL-STD-883 Method 2003	260 Deg, 5 sec 95% Min Covrg	N/A	0/5	Performed by CWT
Coplanarity	JEDEC Spec.	Max = 4 Mil	N/A	0/20	Performed by CWT
Physical Dimension	JEDEC Spec.	Applicable drawing	N/A	0/12	Performed by SPEL
Resistance to	MIL-STD-883		N/A	0/12	Performed by SPEL
Solvent	Method 2015				
Solderability	MIL-STD-883	260 Deg, 5 sec	N/A	0/5	Performed by SPEL
	Method 2003	95% Min Covrg			
Coplanarity	JEDEC Spec.	Max = 4 Mil	N/A	0/20	Performed by SPEL
Physical	JEDEC Spec.	Applicable drawing	N/A	0/12	Performed by SIG-K
Dimension	NAUL OTD CCC		NI/A	0/40	D. (
Resistance to	MIL-STD-883		N/A	0/12	Performed by SIG-K
Solvent	Method 2015	200 Dag 5	NI/A	0/5	Doubours ad by OLO 16
Solderability	MIL-STD-883 Method 2003	260 Deg, 5 sec 95% Min Covrg	N/A	0/5	Performed by SIG-K
Coplanarity	JEDEC Spec.	Max = 4 Mil	N/A	0/20	Performed by SIG-K
Ouplananty	JEDEC Spec.	IVIAX = 4 IVIII	IN/A	0/20	renomied by SiG-N